IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Re Patent Application of:)		
Scott A. Hareland, et al.)	Examiner:	Unassigned
Application No.: Unassigned)	Art Unit:	Unassigned
Filed: Unassigned)		
For: METHOD OF FABRICATING AN ULTRA-NARROW CHANNEL SEMICONDUCTOR DEVICE)))		

Mail Stop Amendment **Commissioner for Patents** P.O. Box 1450 Alexandria, Virginia 22313-1450

INFORMATION DISCLOSURE STATEMENT

Sir:

Enclosed is a copy of Information Disclosure Citation Form PTO-1449 or PTO/SB/08 together with copies of the documents cited on that form, except for copies not required to be submitted (e.g., copies of U.S. patents and U.S. published patent applications need not be enclosed). It is respectfully requested that the cited documents be considered and that the enclosed copy of Information Disclosure Citation Form PTO-1449 or PTO/SB/08 be initialed by the Examiner to indicate such consideration and a copy thereof returned to applicant(s). Please note that the Article from H. Fukuda was previously been cited in an Information Disclosure Statement on July 28, 2003, and is not enclosed.

I hereby certify that this correspondence is being deposited with the United States Postal Service as first class mail with sufficient postage in an envelope addressed to the Commissioner for Patents, P.O. Box 1450, Alexandria, Virginia 22313-1450 on January 27, 2005 (Date of Deposit) Michelle Begay (Typed or printed name of person mailing correspondence)

(Signature of person mailing correspondence)

Pursuant to 37 C.F.R. § 1.97, the submission of this Information Disclosure

Statement is not to be construed as a representation that a search

has been made and is not to be construed as an admission that the information cited in
this statement is material to patentability.

Pursuant to 37 C.F.R. § 1.97, this Information Disclosure Statement is being submitted under one of the following (as indicated by an "X" to the left of the appropriate paragraph):

	37 C.F.R. §1.97(b).
<u>X</u>	37 C.F.R. §1.97(c). If so, then enclosed with this Information Disclosure Statement is <u>one</u> of the following:
<u>X</u>	A statement pursuant to 37 C.F.R. §1.97(e) or
	A check for \$180.00 for the fee under 37 C.F.R. § 1.17(p).
	37 C.F.R. §1.97(d). If so, then enclosed with this Information Disclosure Statement are the following:

- (1) A statement pursuant to 37 C.F.R. §1.97(e); and
- (2) A check for \$180.00 for the fee under 37 C.F.R. §1.17(p) for submission of the Information Disclosure Statement.

If there are any additional charges, please charge Deposit Account No. 02-2666.

Respectfully submitted,

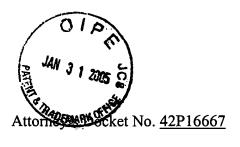
BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

Dated: January 27, 2005

Mimi Diemmy Dao

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12400 Wilshire Blvd. Seventh Floor Los Angeles, CA 90025 (408) 720-8300



PATENT

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In Re Patent Application of:)
Scott A. Hareland, et al.) Examiner: Tran, Mai Huong C.
Application No.: 10/629,039) Art Unit: 2818)
Filed: July 28, 2003 For: METHOD OF FABRICATING AN ULTRA-NARROW CHANNEL SEMICONDUCTOR DEVICE))))
Commissioner for Patents P.O. Box 1450 Alexandria, Virginia 22313-1450	
Sir:	ER 37 C.F.R. §1.97(e)
I hereby certify (as indicated by an ")	X" to the left of the appropriate paragraph):
Information Disclosure Stat from a foreign patent office	on contained in the accompanying ement was first cited in any communication in a counterpart foreign application not more he filing of the Information Disclosure
sufficient postage in an envelope addressed to the Commiss 22313-1450 on January 27, 2005	
Michelle Begay	of Deposit)
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(Signature of person mailing corresponder	nce)

That no item of information contained in the accompanying Information Disclosure Statement was cited in a communication from a foreign patent office in a counterpart foreign application, and, to the knowledge of the undersigned attorney after making reasonable inquiry, no item of information contained in the Information Disclosure Statement was known to any individual designated in §1.56(c) more than three months prior to the filing the Information Disclosure Statement.

Respectfully submitted,

BLAKELY, SOKOLOFF, TAYLOR & ZAFMAN LLP

Dated: January 27, 2005

Mimi Diemmy Dao

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Substitute for Form 1449/PTO			Complete if Known			
O I P INFORMATION DISCLOSURE		Application Number	10/629,039_			
STATEMENT BY APPLICANT (use as many sheets as necessary) 1 of 1		Filing Date	July 28, 2003			
		First Named Inventor:	Scott A. Hareland			
		Art Unit	2818			
		Examiner Name	Tran, Mai H. C.			
Sheekoem	RIF		1 of 1		Attorney Docket Number	42P16667
			U.S. P	ATENT DOCUME	INTS	
Examiner Initials*	Cite No.1	Num	Document Number ber-Kind Code ² (If known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pages, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
 		US-	2003/0006410 A1	01-09-2003	Brian Doyle	<u> </u>
		US-	5,612,255	03-18-1997	Jonathan D. Chapple- Sokol, et al.	
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NON PATENT LITERATURE DOCUMENTS				
Examiner 'Initials*	Cite No ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published	T ²	
		PCT Search Report dated December 28, 2004, 7 pages.		
		TAKAHASHI, Akira, et al., "Si Single-Electron Transistors on SIMOX Substrates," IEICE Electron, Vol. E79-C, November 11, 1996, pages 1503-1508.		
		TSUTSUMI, Toshiyuki, et al., "Close Observation of the Geometrical Features of an Ultranarrow Silicon Nanowire Device," Japanese Journal of Applied Science, Vol. 41, No. 6B, Part 1, June 2002, pages 4419-4422.		

Examiner	Date Considered	
Signature		

*EXAMINER: Initial if reference considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant. ¹Applicant's unique citation designation number (optional). ²See Kinds Codes of USPTO Patent Documents at www.uspto.gov or MPEP 901.04. ³Enter Office that issued the document, by the two-letter code (WIPO Standard ST.3). ⁴For Japanese patent documents, the indication of the year of reign of the Emperor must precede the serial number of the patent document. ⁵Kind of document by the appropriate symbols as indicated on the document under WIPO Standard ST. 16 if possible. ⁸Applicant is to place a check mark here if English language translation is attached.

This collection of information is required by 37 CFR 1.97 and 1.98. The information is required to obtain or retain a benefit by the public which is to file (and by the USPTO to process) an application. Confidentiality is governed by 35 U.S.C. 122 and 37 CFR 1.14. This collection is estimated to take 2 hours to complete including gathering, preparing, and submitting the completed application form to the USPTO. Time will vary depending upon the individual case. Any comments on the amount of time you require to complete this form and/or suggestions for reducing this burden, should be sent to the Chief Information Officer, U.S. Patent and Trademark Office, P.O. Box 1450, Alexandria, VA 22313-1450. DO NOT SENT FEES OR COMPLETED FORMS TO THIS ADDRESS. SEND TO: Commissioner for Patents, P.O. Box 1450, Alexandria, Virginia 22313-1450.

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